

## BC546/547/548/549/550

### **Switching and Applications**

High Voltage: BC546, V<sub>CEO</sub>=65V
Low Noise: BC549, BC550
Complement to BC556 ... BC560

TO-92

1. Collector 2. Base 3. Emitter

# **NPN Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

| Symbol           | Parameter                         | Value     | Units |
|------------------|-----------------------------------|-----------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage : BC546    | 80        | V     |
| 020              | : BC547/550                       | 50        | V     |
|                  | : BC548/549                       | 30        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage : BC546 | 65        | V     |
|                  | : BC547/550                       | 45        | V     |
|                  | : BC548/549                       | 30        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage : BC546/547  | 6         | V     |
|                  | : BC548/549/550                   | 5         | V     |
| I <sub>C</sub>   | Collector Current (DC)            | 100       | mA    |
| P <sub>C</sub>   | Collector Power Dissipation       | 500       | mW    |
| T <sub>J</sub>   | Junction Temperature              | 150       | °C    |
| T <sub>STG</sub> | Storage Temperature               | -65 ~ 150 | °C    |

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

| Symbol                | Parameter                            | Test Condition  | Min. | Тур.              | Max.        | Units          |
|-----------------------|--------------------------------------|---|------|-------------------|-------------|----------------|
| I <sub>CBO</sub>      | Collector Cut-off Current            | $V_{CB}$ =30V, $I_{E}$ =0   |      |                   | 15          | nA             |
| h <sub>FE</sub>       | DC Current Gain                      | V <sub>CE</sub> =5V, I <sub>C</sub> =2mA  | 110  |                   | 800         |                |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA<br>I <sub>C</sub> =100mA, I <sub>B</sub> =5mA               |      | 90<br>200         | 250<br>600  | mV<br>mV       |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage      | I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA<br>I <sub>C</sub> =100mA, I <sub>B</sub> =5mA               |      | 700<br>900        |             | mV<br>mV       |
| V <sub>BE</sub> (on)  | Base-Emitter On Voltage              | $V_{CE}$ =5V, $I_{C}$ =2mA<br>$V_{CE}$ =5V, $I_{C}$ =10mA   | 580  | 660               | 700<br>720  | mV<br>mV       |
| f <sub>T</sub>        | Current Gain Bandwidth Product       | V <sub>CE</sub> =5V, I <sub>C</sub> =10mA, f=100MHz   |      | 300               |             | MHz            |
| C <sub>ob</sub>       | Output Capacitance                   | V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz   |      | 3.5               | 6           | pF             |
| C <sub>ib</sub>       | Input Capacitance                    | V <sub>EB</sub> =0.5V, I <sub>C</sub> =0, f=1MHz  |      | 9                 |             | pF             |
| NF                    | Noise Figure : BC546/547/548         | V <sub>CE</sub> =5V, I <sub>C</sub> =200μA  |      | 2                 | 10          | dB             |
|                       | : BC549/550<br>: BC549<br>: BC550    | $f$ =1KHz, R <sub>G</sub> =2KΩ $V_{CE}$ =5V, I <sub>C</sub> =200 $\mu$ A $R_{G}$ =2KΩ, $f$ =30~15000MHz |      | 1.2<br>1.4<br>1.4 | 4<br>4<br>3 | dB<br>dB<br>dB |

## **h**<sub>FE</sub> Classification

| Classification  | А         | В         | С         |
|-----------------|-----------|-----------|-----------|
| h <sub>FE</sub> | 110 ~ 220 | 200 ~ 450 | 420 ~ 800 |

# **Typical Characteristics**

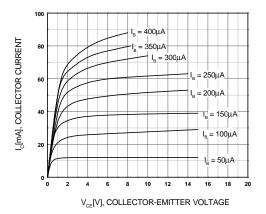


Figure 1. Static Characteristic

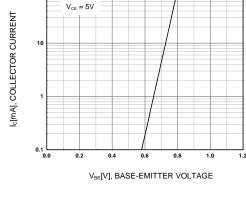


Figure 2. Transfer Characteristic

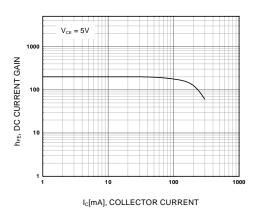


Figure 3. DC current Gain

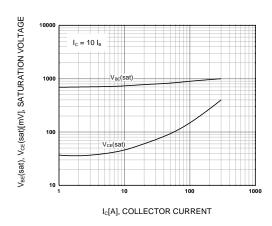


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

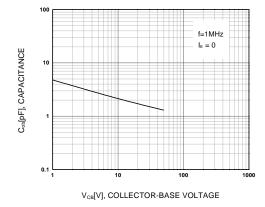


Figure 5. Output Capacitance

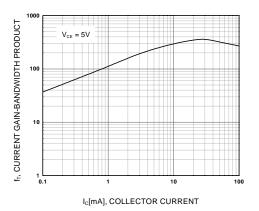
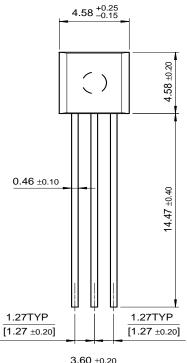


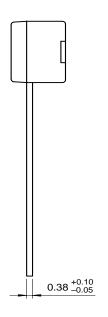
Figure 6. Current Gain Bandwidth Product

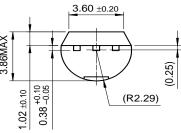
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# **Package Dimensions**

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Dimensions in Millimeters

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| Bottomless™                | FAST <sup>®</sup>    | LittleFET™             | Power247™                | SuperSOT™-3           |
| CoolFET™                   | FASTr™               | MicroFET™              | PowerTrench <sup>®</sup> | SuperSOT™-6           |
| CROSSVOLT™                 | FRFET™               | MicroPak™              | QFET™                    | SuperSOT™-8           |
| DOME™                      | GlobalOptoisolator™  | MICROWIRE™             | $QS^{TM}$                | SyncFET™              |
| EcoSPARK™                  | GTO™                 | MSX™                   | QT Optoelectronics™      | TinyLogic™            |
| E <sup>2</sup> CMOS™       | HiSeC™               | MSXPro™                | Quiet Series™            | TruTranslation™       |
| EnSigna™                   | $I^2C^{TM}$          | $OCX^{TM}$             | RapidConfigure™          | UHC™                  |
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